# 53030

#### FEATURES

- IAW DESC Drawing 87042
- SPST, Normally Open
- Up to 1200 V RMS Isolation CMOS or TTL Compatible Input
- Power FET Output for Low On-state Resistance
- Full Military Temperature Operation:
  -55°C to +110°C
  Military Environmental Screening Available
- Improved Thermal Characteristics
- Built and tested per Y level screening requirement of MIL-R-28750

#### **GENERAL DESCRIPTION**

The MII 53030 is a military SPST solid-state relay. This light-weight device is resistant to damage from shock and vibration, and immune to contact-related problems (contamination, arcing) associated with mechanical equivalents.

Optical coupling between the input and output stages provides effective isolation up to 1200 volts AC RMS. Power FET outputs eliminate bipolar offset, and minimize output voltage drop.

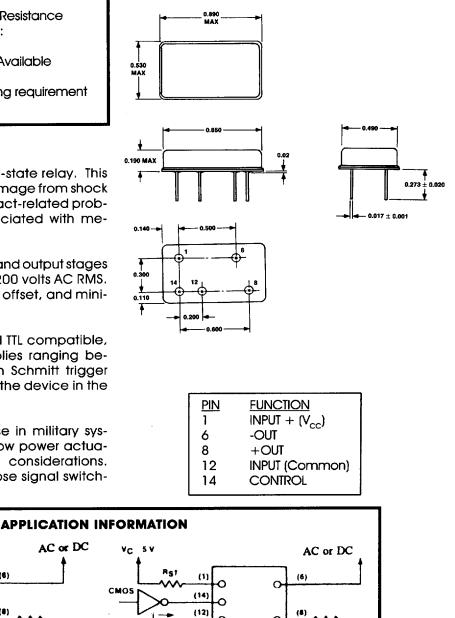
The control input logic is CMOS and TL compatible, and will accommodate bias supplies ranging between 3.8 and 32 VDC. A built-in Schmitt trigger increases noise margin when using the device in the CMOS input mode.

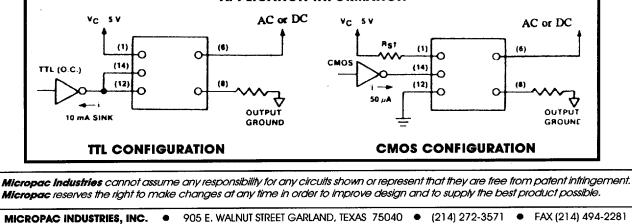
This solid-state relay is ideal for use in military systems, or wherever high reliability, low power actuation, and light weight are design considerations. Applications include general purpose signal switching and electronic load control.



### MILITARY, DC SOLID STATE RELAY WITH SHORT CIRCUIT PROTECTION

#### PACKAGE DIMENSIONS





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## TABLE 1

## LIMITING RESISTANCE (R<sub>s</sub>) VALUES (Without Heat Sink)

V(VDC)	3.8-6	6-10	10-14	14-18	18-22	22-26	26-32
R(Ω)		300	620	910	1200	1500	2000
Rating (W)		1/4	1/4	1/2	1/2	1/2	1

### **ABSOLUTE MAXIMUM RATINGS**

Isolation V	'ołłage1	200 VAC RMS
Operating	) Temperature	C to +110°C
Storage	Temperature	C to +125°C

## **ELECTRICAL CHARACTERISTICS\*** $I_A = +25^{\circ}C$

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
Input (Control) Characteristics TTL Configuration					
Input Current			13	16	mA
Control Voltage Range	See Table 1 - Bias Resistance	3.8		32	VDC
Turn-Off Voltage Maximum				1.5	VDC
Turn-On Voltage Minimum		3.8			VDC
Input (Control) Characteristics CMOS Configuration					
Input Current			25	250	μΑ
Control Voltage Range		· · · · ·		18	VDC
Bias Supply - V <sub>c</sub>	See Table 1 - Bias Resistance	3.8		32	VDC
Bias Current			13	16	mA
Turn-Off Voltage @ 5 V V <sub>c</sub>		···	3.2		VDC
Turn-On Voltage		0.5	+ +		VDC
Total Schmitt Hysteresis		1.0			VDC
Maximum Continuous Operating				w	
Output Voltage			±60 Volts Peak		VDC
Maximum Load Current	25 °C		.95	i	Amps
On Resistance -Maximum	25 °C		.70		Ohms
Current Surge	100 mS @ 25 °C		2		Amps
Overload Trip Current	40 mS Pulse @ 25 °C		8.5		Amps
Typical Thermal Resistance, 0JA			70		°C/W
ALÐ		- <u> </u>	25	· · · · · · · · · · · · · · · · · · ·	°C/W
Typical ON, t <sub>on</sub>		-	3.0		m\$
Typical OFF, t off			4.0		mS
Typical Leakage Current	60 V		100		μΑ
Minimum Dielectric Strength			1200		V RMS
Typical Isolation Resistance	Input to Case, 500 V		10%		Ohms

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